NSN 5961-01-587-5176

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View Online at https://aerobasegroup.com/nsn/5961-01-587-5176
Overall Length:
Between 2.229 inches and 2.269 inches
Overall Height:
Between 0.790 inches and 0.830 inches
Overall Width:
Between 1.219 inches and 1.259 inches
End Application:
9515-01-563-0360; kit, armor, medium crawler tractor
Mounting Facility Quantity:
4
Mounting Method:
Unthreaded hole
Product Name:
High pulse power transzorb
Special Features:
Height of post: 0.200 inch; center line distance to center line distance of posts: 0.584 inch; mounting holes diameter: 0.120 inch; peak
pulse power dissipation at 25 degree c, 1ms, 60 kw, steady state power dissipation at 25 degree c 40 watts, t clamping 0 volts to (br) minus
1x 10 -8 seconds; operating and storage temp: minus 55, plus 150 degree c; reverse stand-off voltage vmw (volts) 33; reverse leakage at
vwm ld (ua) 25; breakdown voltage at 10 ma v(br)(volts) 36.7; maximim clamping voltage at ipp vc (volts) 49; maximim peak pulse current
ipp (amps) 120; protection leverl: mil-std-1275 compliant; 100v surge withstanding with 0.5-ohm source impendance non-hermetic version
Terminal Type And Quantity:
2 binding post
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig: